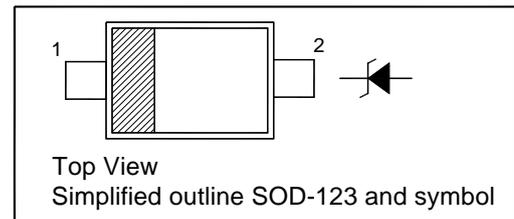


Features

- Ideally suited for automated assembly processes
- Total power dissipation: max. 500 mW

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Power Dissipation	P_{tot}	500	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Max.	Unit
Thermal Resistance Junction to Ambient Air	R_{thA}	340	$^\circ\text{C}/\text{W}$
Forward Voltage at $I_F = 10 \text{ mA}$	V_F	0.9	V

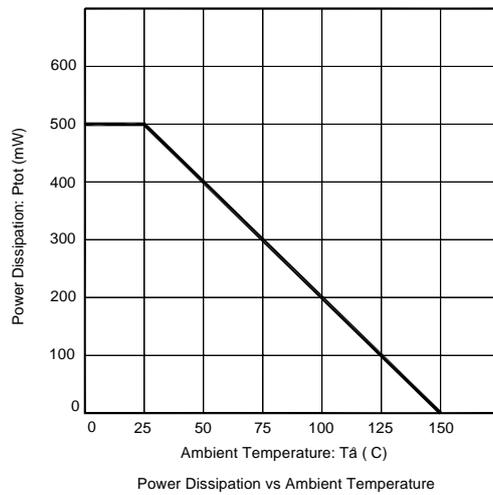
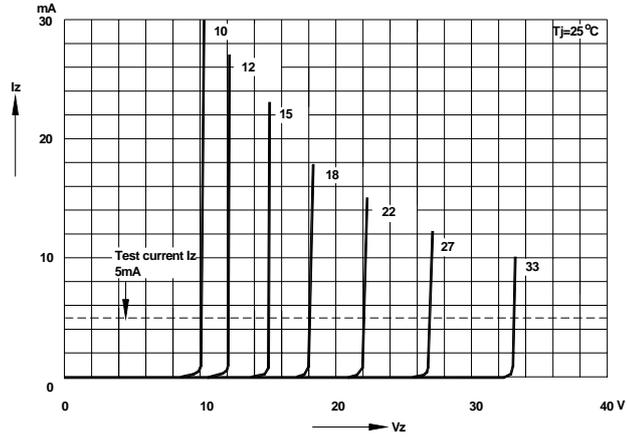
Characteristics at $T_a = 25^\circ\text{C}$

Type	Marking Code	Zener Voltage Range ¹⁾			Dynamic Impedance				Reverse Leakage Current	
		V_{znom}	V_{ZT}	at I_{ZT}	Z_{ZT}	at I_{ZT}	Z_{ZK}	at I_{ZK}	I_{R}	at V_{R}
		V	V	mA	Max. (Ω)	mA	Max. (Ω)	mA	Max. (μA)	V
BZT52C16	WK	16	15.3...17.1	5	40	5	200	1	0.1	11.2

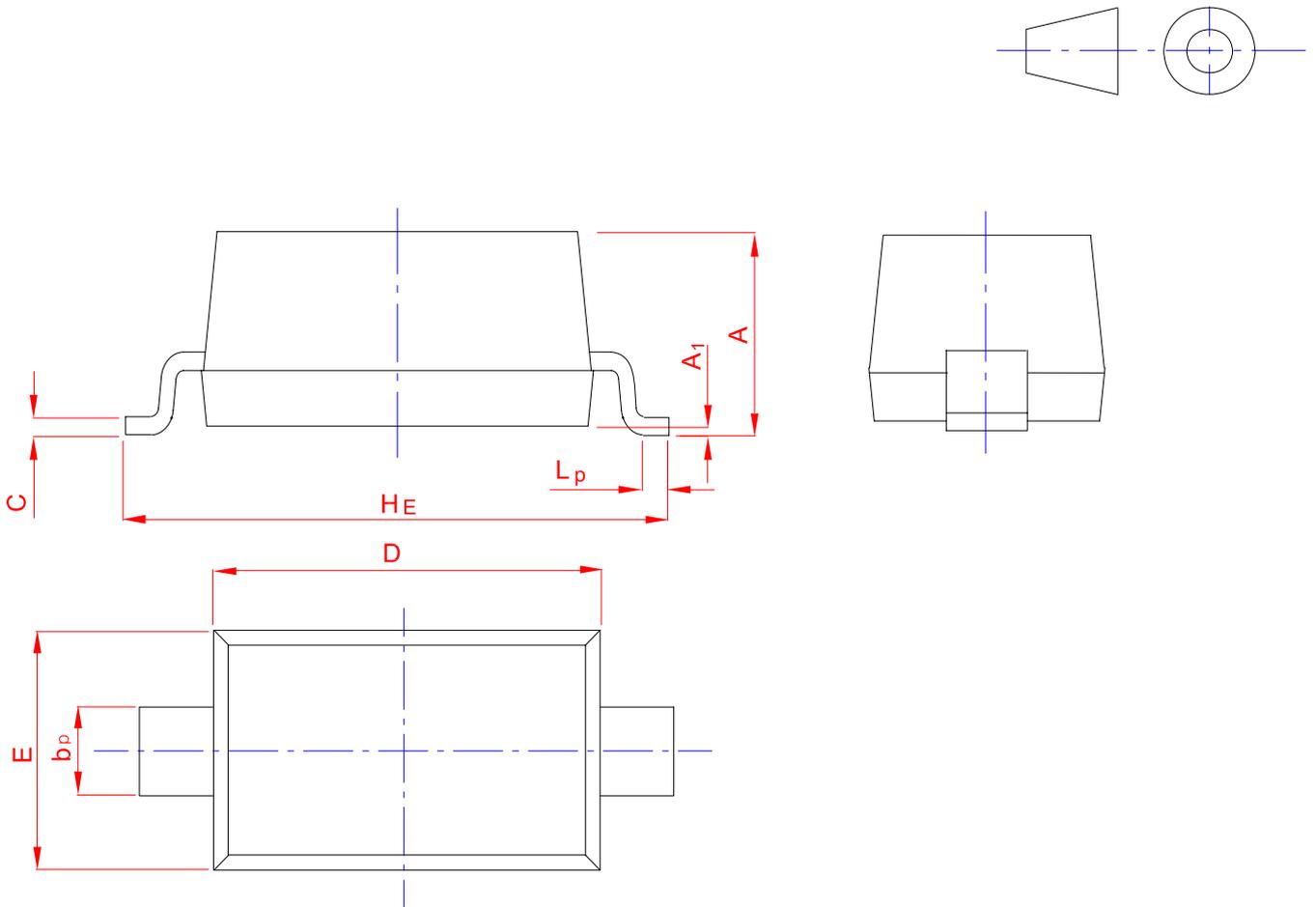
¹⁾ V_{ZT} is tested with pulses (20 ms).



Breakdown characteristics
T_j = constant (pulsed)



Power Dissipation vs Ambient Temperature



UNIT	A	b _p	C	D	E	HE	A ₁	L _p
mm	1.20	0.60	0.135	2.75	1.65	3.85	0.10	0.50
	0.90	0.50	0.100	2.55	1.55	3.55	0.01	0.20